

※ 考生請注意：本試題不可使用計算機。 請於答案卷(卡)作答，於本試題紙上作答者，不予計分。

1. (a) As shown in Figure 1, the five forward I-V curves correspond to five p-n junction diodes made from different semiconductors with corresponding energy band gap $E_{g1}, E_{g2}, E_{g3}, E_{g4}$ and E_{g5} . Please identify which of the following item(s) is(are) true. (A) $E_{g3} > E_{g4}$ (B) $E_{g5} > E_{g4}$ (C) $E_{g3} < E_{g4}$ (D) $E_{g3} > E_{g2} > E_{g1}$ (E) $E_{g1} > E_{g2} > E_{g3}$ (3%)

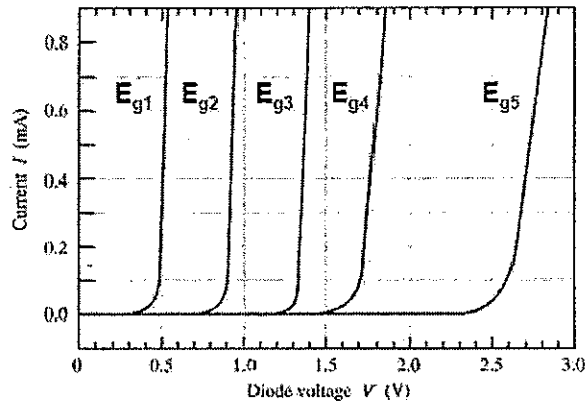


Figure 1

- (b) As shown in Figure 2, if the five forward I-V curves correspond to a P-N diode operated at different temperatures, which of the following item(s) is(are) true. (A) $T_1 > T_2$ (B) $T_3 > T_4$ (C) $T_2 > T_5$ (D) $T_3 > T_2$ (E) $T_5 > T_4$ (2%)

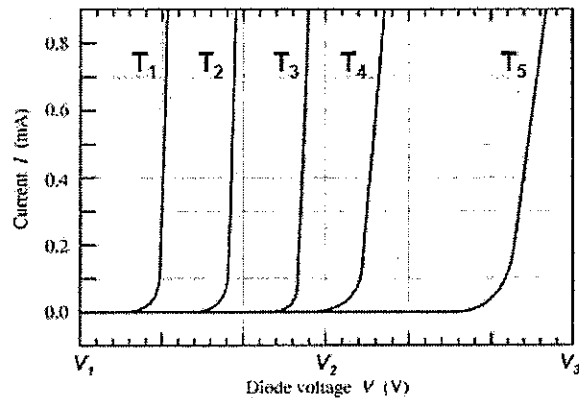


Figure 2

2. As shown in Figure 3, assuming the p-n and Zener diodes are ideal, and $V_z = 5V$, please find $V_2 = \underline{\hspace{2cm}} V$ and $V_3 = \underline{\hspace{2cm}} V$ when the voltage of V_1 is 6 V. (10%)

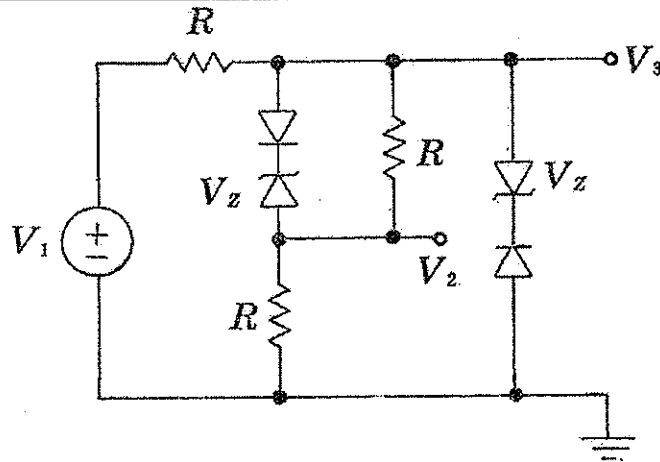


Figure 3

3. As shown in Figure 4, the current meter (M) with a full scale of $50 \mu\text{A}$ and a negligible resistance.
- (a) Assuming the transistor has $V_{BE}=0.7 \text{ V}$ at $I_E=1 \text{ mA}$, what value of R_C would establish a resistor current of 1 mA ? (b) what value of β would result in the current meter(M) at a full-scale reading? (c) what is β if the meter reading is $5 \mu\text{A}$? (15%)

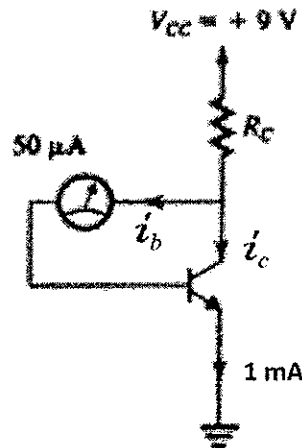


Figure 4

4. Figure 5 shows a CMOS amplifier. $|V_{TN}| = |V_{TP}| = 1\text{V}$, $K_n=4K_p=100\mu\text{A}/\text{V}^2$, V_{TN} and V_{TP} are the threshold voltages of the NMOS and PMOS FETs, respectively. $K_{n(p)}=\mu_{n(p)}C_{ox}W/2L$, where $\mu_{n(p)}$ is the electron(hole) mobility, C_{ox} is the oxide capacitance, W is the gate width, and L is the gate length.
- (a) what is the $V_D=$ ___ V, and drain bias current $I_D=$ ___ mA. (10%) (b) Assuming the output resistance of NMOS and PMOS FETs are infinite, what is the small signal gain $v_o/v_i=$ ___, and input resistance, $R_{in}=$ ___ Ω . (10%)

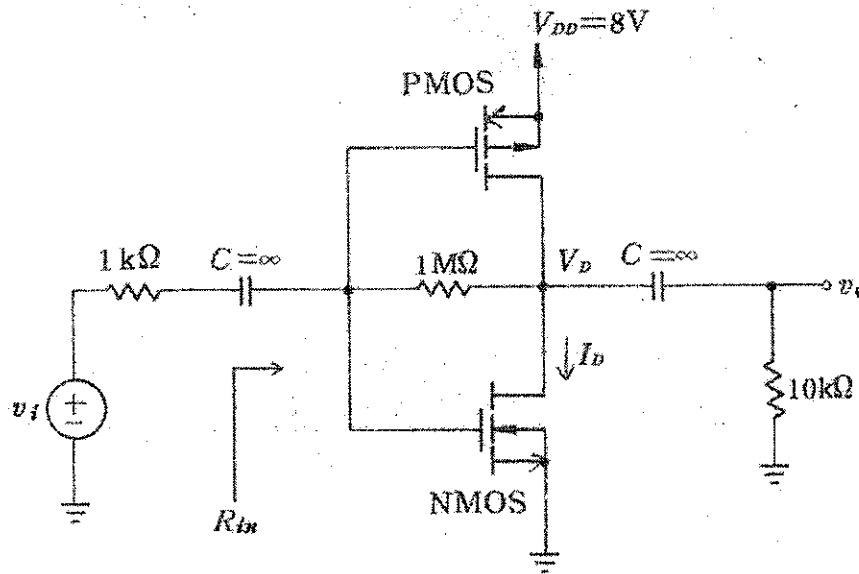


Figure 5

5. Figure 6 shows an ideal amplifier having a gain of -100 V/V with an impedance Z connected between its output and input terminals. Find the Miller equivalent circuit when Z is (a) a $1\text{-M}\Omega$ resistance and (b) a 1-pF capacitance. In each case, please plot the equivalent circuit and use the equivalent circuit to determine V_o/V_{sig} . (10 %)

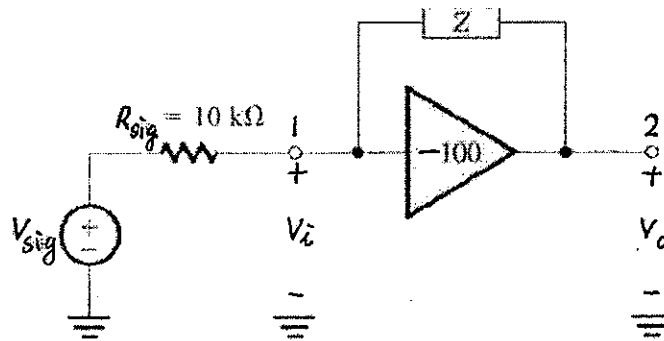


Figure 6

6. (20 %) (Frequency Response) Consider the common-emitter amplifier of Figure 7 under the following conditions: $R_{sig}=5 \text{ k}\Omega$, $R_1=33 \text{ k}\Omega$, $R_2=22 \text{ k}\Omega$, $R_E=3.9 \text{ k}\Omega$, $R_C=4.7 \text{ k}\Omega$, $R_L=5.6 \text{ k}\Omega$, $V_{CC}=5 \text{ V}$. The dc emitter current can be shown to be $I_E \cong 0.3 \text{ mA}$, at which $\beta=120$, $r_o=300 \text{ k}\Omega$ and $r_x=50\Omega$.

(a) If the transistor is specified to have $f_T=700 \text{ MHz}$ and $C_\mu=1 \text{ pF}$, find the upper 3-dB frequency.

(b) Design the coupling and bypass capacitors for a lower 3-dB frequency of 100 Hz . Design so that the contribution of each of C_{C1} and C_{C2} to determining is only 5%.

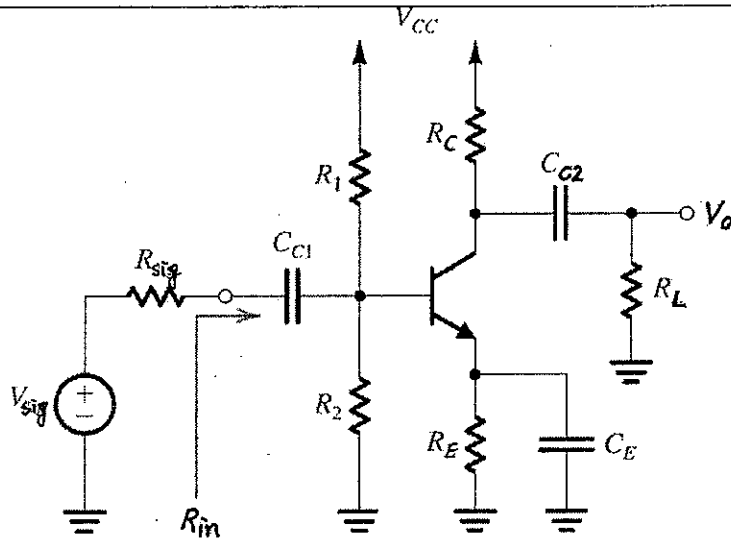


Figure 7

7. (10 %) Consider the Op-amp circuit shown in Figure 8, where the op amp has infinite input resistance and zero output resistance but finite open-loop gain A .

(a) Replace the op-amp with its equivalent circuit model and show that $\beta = R_1 / (R_1 + R_2)$

(b) If $R_1 = 10 \text{ k}\Omega$, find R_2 that results in $A_f = 10 \text{ V/V}$ for the following three cases: (i) $A = 1000 \text{ V/V}$; (ii) $A = 100 \text{ V/V}$; (iii) $A = 12 \text{ V/V}$.

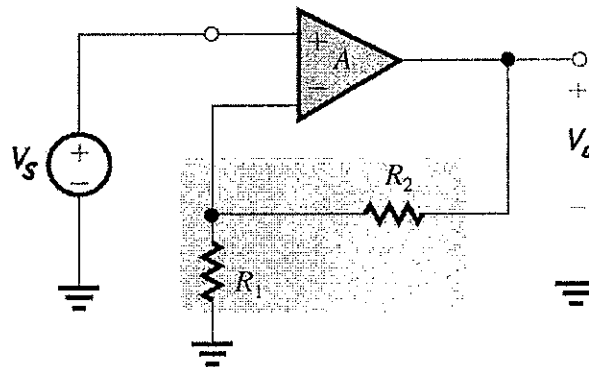


Figure 8

8. (10 %) For the negative-feedback loop, find the loop gain $A\beta$ for which the sensitivity of closed-loop gain to open-loop gain is -20 dB. For what value of does the sensitivity become 1/2?

